

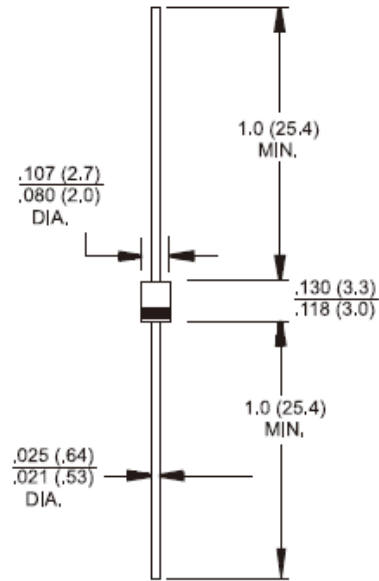
TS-1

Features

- High efficiency, low VF
- High current capability
- High reliability
- High surge current capability
- Low power loss
- For use in low voltage, high frequency inverter, Free wheeling, and polarity protection application
- Green compound with suffix "G" on packing code & prefix "G" on datecode

Mechanical Data

- Case: Molded plastic
- Epoxy: UL 94V-0 rate flame retardant
- Lead: Pure tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
- Polarity: Color band denotes cathode
- High temperature soldering guaranteed: 260°C/10 seconds/.375"(.95mm) lead lengths at 5 lbs., (2.3kg) tension
- Mounting position: Any
- Weight: 0.20 grams



Dimensions in inches and (millimeters)

Marking Diagram



- SFT1XG = Specific Device Code
G = Green Compound
Y = Year
M = Work Month

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	SFT 11G	SFT 12G	SFT 13G	SFT 14G	SFT 15G	SFT 16G	SFT 17G	SFT 18G	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	150	200	300	400	500	600	V
Maximum RMS Voltage	V _{RMS}	35	70	105	140	210	280	350	420	V
Maximum DC Blocking Voltage	V _{DC}	50	100	150	200	300	400	500	600	V
Maximum Average Forward Rectified Current	I _{F(AV)}	1								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	30								A
Maximum Instantaneous Forward Voltage (Note 1) @ 1 A	V _F	0.95				1.3		1.7		V
Maximum DC Reverse Current at Rated @ T _A =25 °C	I _R	5								uA
DC Blocking Voltage @ T _A =125 °C		100								uA
Maximum Reverse Recovery Time (Note 2)	T _{rr}	35								nS
Typical Junction Capacitance (Note 3)	C _j	20				10				pF
Typical Thermal Resistance	R _{θJA}	100								°C/W
Operating Temperature Range	T _J	- 65 to + 150								°C
Storage Temperature Range	T _{STG}	- 65 to + 150								°C

Note 1: Pulse Test with PW=300 usec, 1% Duty Cycle

Note 2: Reverse Recovery Test Conditions: $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{RR}=0.25\text{A}$

Note 3: Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.

RATINGS AND CHARACTERISTIC CURVES (SFT11G THRU SFT18G)

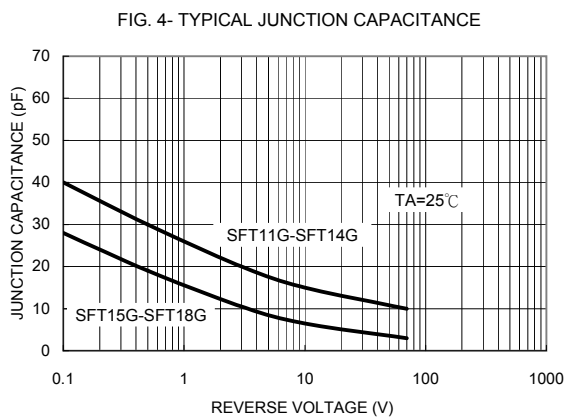
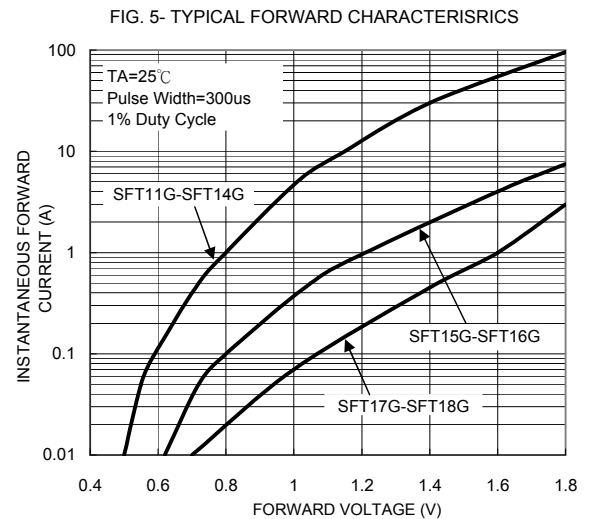
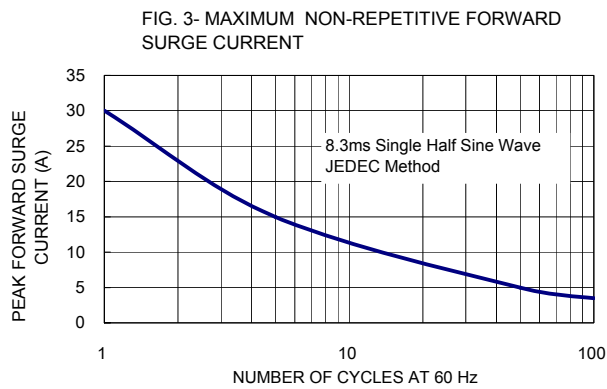
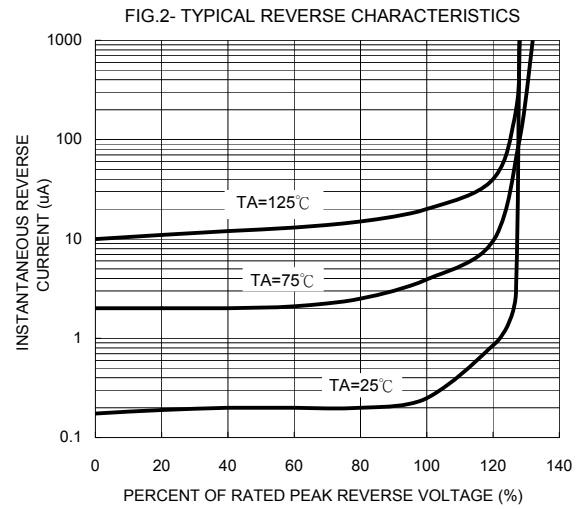
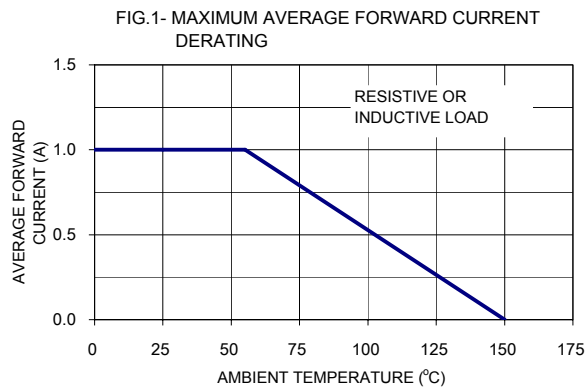


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

